COMPLIANT

HALOGEN FREE

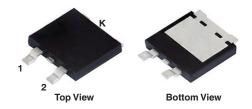


## Vishay General Semiconductor

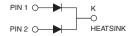
# **Dual Low-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.34 \text{ V}$  at  $I_F = 5.0 \text{ A}$ 

## TMBS® eSMP® Series SMPD (TO-263AC)



#### V60DM60C



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>RRM</sub> 60 V				
I <sub>FSM</sub>	320 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A (T <sub>A</sub> = 125 °C)	0.61 V			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Diode variations	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

#### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V60DM60C	UNIT	
Device marking code			V60DM60C		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> (1)	60	Α	
	per diode		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	320	А	
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +175	- °C	
Storage temperature range		T <sub>STG</sub>	-55 to +175		

#### Notes

<sup>(1)</sup> Mounted on infinite heatsink

 $<sup>^{(2)}</sup>$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$ 



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.46	-	. V
	I <sub>F</sub> = 15 A			0.55	-	
	I <sub>F</sub> = 30 A			0.65	0.71	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.34	-	
	I <sub>F</sub> = 15 A			0.47	-	
	I <sub>F</sub> = 30 A			0.61	0.67	
Reverse current at rated V <sub>R</sub> per diode	V <sub>B</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	2.1	- mA
	v <sub>R</sub> = 00 v	T <sub>A</sub> = 125 °C		12	35	
Typical junction capacitance	4.0 V, 1 MHz		CJ	3400	-	pF

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5 \text{ ms}$ 

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	METER SYMBOL V60DM60C		UNIT	
Typical thermal resistance per device	R <sub>θJC</sub> <sup>(1)</sup>	0.8	°C/W	
	R <sub>0JA</sub> (2)(3)	50	] 5/W	

### Notes

- (1) Mounted on infinite heatsink
- $^{(2)} \ \ The \ heat \ generated \ must \ be \ less \ than \ the \ thermal \ conductivity \ from \ junction-to-ambient: \ dP_D/dT_J < 1/R_{\theta JA} \ \ junction-to-ambient \ dP_D/dT_J < 1/R_{\theta JA} \ \ junct$
- (3) Free air, without heatsink

ORDERING INFORMATION (Example)					
PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE		BASE QUANTITY	DELIVERY MODE		
V60DM60C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel	
V60DM60CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified

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## **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

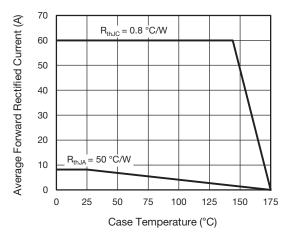


Fig. 1 - Maximum Forward Current Derating Curve

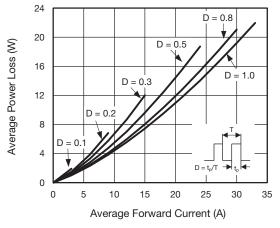


Fig. 2 - Average Power Loss Characteristics

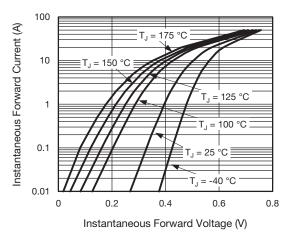


Fig. 3 - Typical Instantaneous Forward Characteristics

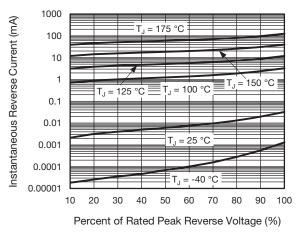


Fig. 4 - Typical Reverse Leakage Characteristics

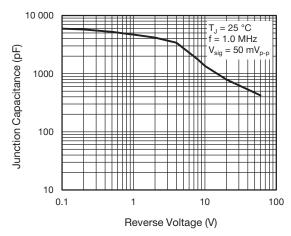


Fig. 5 - Typical Junction Capacitance

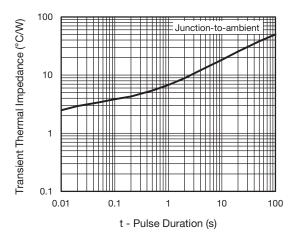


Fig. 6 - Typical Transient Thermal Impedance

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0.052 (1.23)

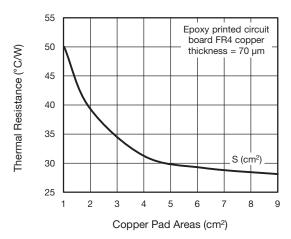
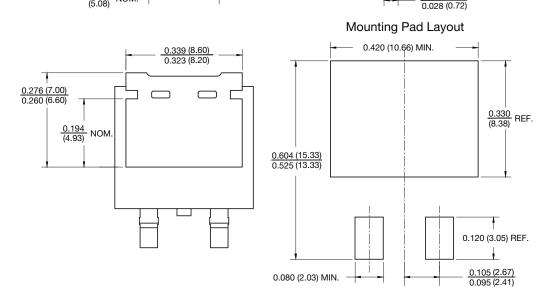


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### SMPD (TO-263AC) 0.402 (10.20) 0.071 (1.80) 0.386 (9.80) 0.020 (0.52) 0.011 (0.27) 0.063 (1.60) 0.059 (1.50) REF 0.048 (1.21) 0.032 (0.81) 0.354 (8.99) 0.338 (8.59) 0.509 (12.93) 0.485 (12.33) 0 to 0.01 (0 to 0.254) 0.069 (1.74) 0.053 (1.34) 0.063 (1.60) 0.020 (0.52) 0.047 (1.20) 0.011 (0.27)





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